MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Broduct data sheet



Features

- 350Watts peak pulse power (tp = $8/20\mu$ s)
- Low clamping voltage
- Low leakage current
- Protection one power line
- Low Capacitance: 1.0 pF Typical
- IEC 61000-4-2 ±20kV contact ±20kV air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 20A (8/20µs)



SOD-323

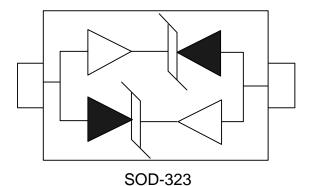
Applications

- Ethernet 10/100/1000 Base T
- Cellular Phones
- Handheld Wireless Systems
- Personal Digital Assistant (PDA)
- **USB** Interface

Mechanical Data

- SOD-323 package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

Schematic & PIN Configuration





Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power (t _p =8/20μs)	P _{PP}	350	Watts
Peak Pulse Current (t _p =8/20μs) (note1)	I _{pp}	20	А
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V _{ESD}	20 20	kV
Lead Soldering Temperature	T∟	260(10seconds)	$^{\circ}$ C
Junction Temperature	TJ	-55 to + 150	$^{\circ}$ C
Storage Temperature	T _{stg}	-55 to + 150	$^{\circ}$ C

Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				3.3	٧
Reverse Breakdown Voltage	V_{BR}	I _T =1mA	4.0			V
Reverse Leakage Current	I _R	V _{RWM} =3.0V,T=25℃			1	uA
Clamping Voltage	V _C	I _{PP} =20A,t _p =8/20μs			18	V
Junction Capacitance	C _j	$V_R = 0V$, $f = 1MHz$		1.0	1.5	pF

Electrical Parameters (TA = 25°C unless otherwise noted)

Symbol	Parameter
I PP	Maximum Reverse Peak Pulse Current
Vc	Clamping Voltage @ IPP
VRWM	Working Peak Reverse Voltage
lr	Maximum Reverse Leakage Current @ VRWM
V _{BR}	Breakdown Voltage @ I _T
lτ	Test Current

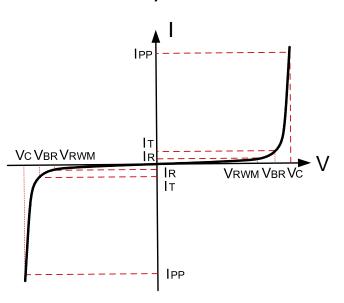




Figure 1: Peak Pulse Power vs. Pulse Time

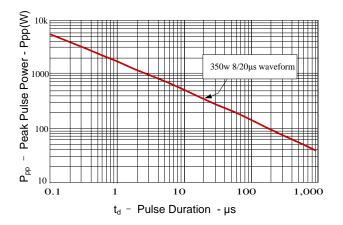


Figure 2: Power Derating Curve

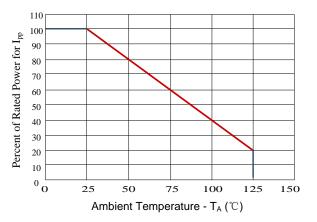


Figure3: Pulse Waveform

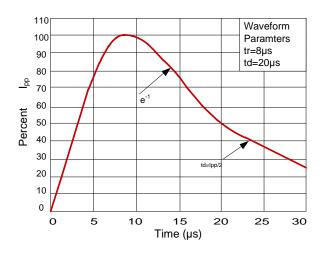
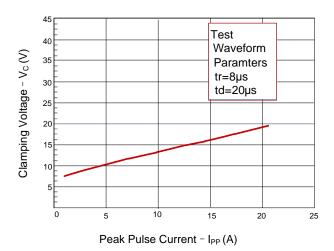


Figure 4: Clamping Voltage vs.lpp

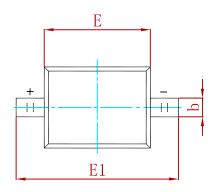


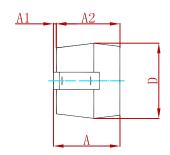


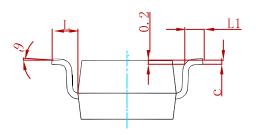
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PACKAGE MECHANICAL DATA

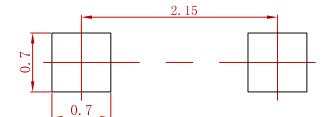






Cumbal	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min.	Max.	Min.	Max.
Α		1.000		0.039
A 1	0.000	0.100	0.000	0.004
A2	0.800	0.900	0.031	0.035
b	0.250	0.350	0.010	0.014
С	0.080	0.150	0.003	0.006
D	1.200	1.400	0.047	0.055
E	1.600	1.800	0.063	0.071
E1	2.550	2.750	0.100	0.108
L	0.475 REF.		0.019 REF.	
L1	0.250	0.400	0.010	0.016
θ	0°	8°	0°	8°

Suggested Pad Layout



Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
SP4020-01FTG-C-MS	SOD-323	3000



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